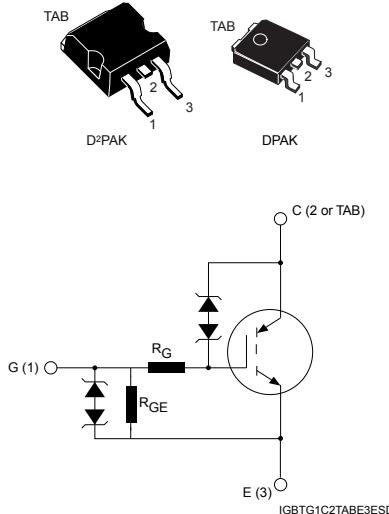


### Automotive-grade 450 V internally clamped IGBT EsCIS 300 mJ

## Features



- AEC-Q101 qualified
- SCIS energy of 300 mJ @ T<sub>J</sub> = 25 °C
- Parts are 100% tested in SCIS
- ESD gate-emitter protection
- Gate-collector high voltage clamping
- Logic level gate drive
- Very low saturation voltage
- High pulsed current capability
- Gate and gate-emitter resistor



## Applications

- Automotive ignition coil driver circuit

## Description

This application-specific IGBT utilizes the most advanced PowerMESH technology optimized for coil driving in the harsh environment of automotive ignition systems. These devices show very low on-state voltage and very high SCIS energy capability over a wide operating temperature range. Moreover, ESD-protected logic level gate input and an integrated gate resistor means no external protection circuitry is required.



Product status	
STGB20N45LZAG	
STGD20N45LZAG	

Product summary	
Order code	STGB20N45LZAG
Marking	GB20N45LZ
Package	D <sup>2</sup> PAK
Packing	Tape and reel
Order code	STGD20N45LZAG
Marking	GD20N45LZ
Package	DPAK
Packing	Tape and reel

## 1 Electrical ratings

**Table 1. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CES}$	Collector-emitter voltage ( $V_{GE} = 0$ V)	$V_{CES(\text{clamped})}$	V
$V_{ECS}$	Emitter-collector voltage ( $V_{GE} = 0$ V)	20	V
$I_C$	Continuous collector current at $T_C = 25$ °C, $V_{GE} = 4$ V	25	A
	Continuous collector current at $T_C = 100$ °C, $V_{GE} = 4$ V	25	A
$I_{CP}$ <sup>(1)</sup>	Pulsed collector current	50	A
$V_{GE}$	Gate-emitter voltage	$V_{GE(\text{clamped})}$	V
$P_{TOT}$	Total power dissipation at $T_C = 25$ °C	150	W
$E_{SCIS\_25}$ <sup>(2)</sup>	Self-clamping inductive switching energy	300	mJ
$E_{SCIS\_150}$ <sup>(3)</sup>	Self-clamping inductive switching energy @ $T_J = 150$ °C	170	mJ
ESD	Human body model, $R = 1.5$ kΩ, $C = 100$ pF	4	kV
	Charged device model	2	kV
$T_{STG}$	Storage temperature range	-55 to 175	°C
$T_J$	Operating junction temperature range		°C

1. Pulse width limited by maximum junction temperature.
2. Starting  $T_J = 25$  °C,  $L = 3$  mH,  $R_g = 1$  kΩ,  $V_{cc} = 50$  V during inductor charging and  $V_{cc} = 0$  V during the time in clamp. Parts are 100% electrically tested in production.
3. Starting  $T_J = 150$  °C,  $L = 3$  mH,  $R_g = 1$  kΩ,  $V_{cc} = 50$  V during inductor charging and  $V_{cc} = 0$  V during the time in clamp.

**Table 2. Thermal data**

Symbol	Parameter	Value		Unit
		D²PAK	DPAK	
$R_{thj\text{-case}}$	Thermal resistance junction-case	1		°C/W
$R_{thj\text{-amb}}$	Thermal resistance junction-ambient	62.5	100	°C/W

## 2 Electrical characteristics

$T_C = 25^\circ\text{C}$  unless otherwise specified

**Table 3. Static characteristics**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{CES(\text{clamped})}$	Collector-emitter clamped voltage	$I_C = 2 \text{ mA}, V_{GE} = 0 \text{ V}$		450		V
		$I_C = 2 \text{ mA}, V_{GE} = 0 \text{ V}, T_J = -40^\circ\text{C} \text{ to } 175^\circ\text{C}$	415		475	V
$V_{(BR)ECS}$	Emitter-collector break-down voltage	$I_C = 75 \text{ mA}, V_{GE} = 0 \text{ V}$	20			V
$V_{GE(\text{clamped})}$	Gate-emitter clamped voltage	$I_G = \pm 2 \text{ mA}, T_J = -40^\circ\text{C} \text{ to } 175^\circ\text{C}$	12		16	V
$V_{CE(\text{sat})}$	Collector-emitter saturation voltage	$V_{GE} = 4 \text{ V}, I_C = 6 \text{ A}$		1.1	1.25	V
		$V_{GE} = 4.5 \text{ V}, I_C = 10 \text{ A}, T_J = 175^\circ\text{C}$		1.25	1.55	V
$V_{GE(\text{th})}$	Gate-threshold voltage	$V_{GE} = V_{CE}, I_C = 1 \text{ mA}$	1.3	1.7	2.1	V
		$V_{GE} = V_{CE}, I_C = 1 \text{ mA}, T_J = 175^\circ\text{C}$		1.05		V
$I_{CES}$	Collector cut-off current	$V_{CE} = 15 \text{ V}, V_{GE} = 0 \text{ V}, T_J = 150^\circ\text{C}$			20	$\mu\text{A}$
		$V_{CE} = 200 \text{ V}, V_{GE} = 0 \text{ V}, T_J = 150^\circ\text{C}$			100	$\mu\text{A}$
$I_{GES}$	Gate-emitter leakage current	$V_{GE} = \pm 10 \text{ V}, V_{CE} = 0 \text{ V}$		625		$\mu\text{A}$
		$V_{GE} = \pm 10 \text{ V}, V_{CE} = 0 \text{ V}, T_J = -40^\circ\text{C} \text{ to } 175^\circ\text{C}$	450		900	$\mu\text{A}$
$R_{GE}$	Gate emitter resistance		11	16	22	$\text{k}\Omega$
$R_G$	Gate resistance			120		$\Omega$

**Table 4. Dynamic characteristics**

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$C_{ies}$	Input capacitance	$V_{CE} = 25 \text{ V}, f = 1 \text{ MHz}, V_{GE} = 0 \text{ V}$	-	1011	-	pF
$C_{oes}$	Output capacitance		-	87	-	
$C_{res}$	Reverse transfer capacitance		-	14	-	
$Q_g$	Total gate charge	$V_{CE} = 13 \text{ V}, I_C = 10 \text{ A}, V_{GE} = 0 \text{ to } 5 \text{ V}$	-	26	-	nC

**Table 5. Resistive load switching characteristics**

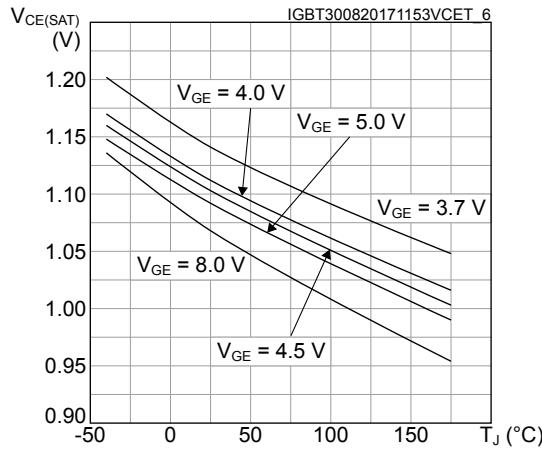
Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$	Turn-on delay time	$V_{CC} = 14 \text{ V}, V_{GE} = 5 \text{ V},$ $R_L = 1 \Omega, R_G = 1 \text{k}\Omega$ (see <a href="#">Figure 17. Test circuit for resistive load switching</a> )	-	1.1	-	$\mu\text{s}$
$t_r$	Current rise time		-	3.6	-	$\mu\text{s}$
$t_{d(on)}$	Turn-on delay time	$V_{CC} = 14 \text{ V}, V_{GE} = 5 \text{ V},$ $R_L = 1 \Omega, R_G = 1 \text{k}\Omega,$ $T_J = 150^\circ\text{C}$ (see <a href="#">Figure 17. Test circuit for resistive load switching</a> )	-	1.06	-	$\mu\text{s}$
$t_r$	Current rise time		-	3.5	-	$\mu\text{s}$

**Table 6. Inductive load switching characteristics**

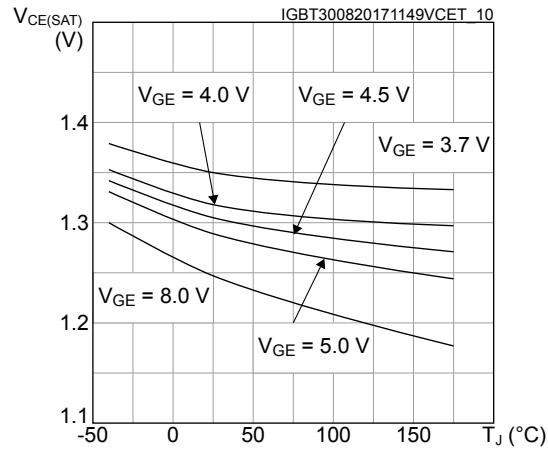
Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(off)}$	Turn-off delay time	$V_{CC} = 300 \text{ V}, L = 1 \text{ mH},$ $I_C = 10 \text{ A}, V_{GE} = 5 \text{ V},$ $R_G = 1 \text{k}\Omega$	-	7.3	-	$\mu\text{s}$
$t_f$	Current fall time		-	4.6	-	$\mu\text{s}$
$dV/dt$	Turn-off voltage slope	(see <a href="#">Figure 16. Test circuit for inductive load switching</a> )	-	165	-	$\text{V}/\mu\text{s}$
$t_{d(off)}$	Turn-off delay time		-	7.5	-	$\mu\text{s}$
$t_f$	Current fall time	$I_C = 10 \text{ A}, V_{GE} = 5 \text{ V},$ $R_G = 1 \text{k}\Omega, T_J = 150^\circ\text{C}$	-	8.2	-	$\mu\text{s}$
$dV/dt$	Turn-off voltage slope		-	116	-	$\text{V}/\mu\text{s}$

## 2.1 Electrical characteristics (curves)

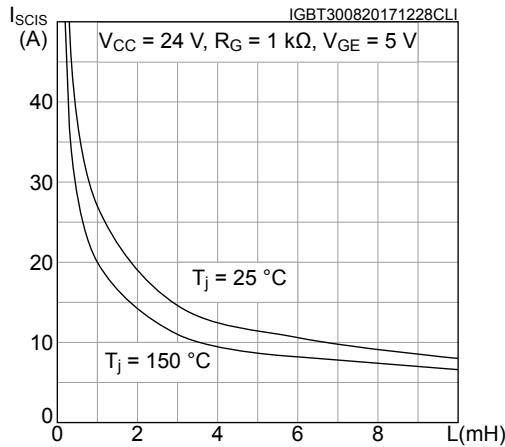
**Figure 1.**  $V_{CE(sat)}$  vs junction temperature ( $I_C = 6 \text{ A}$ )



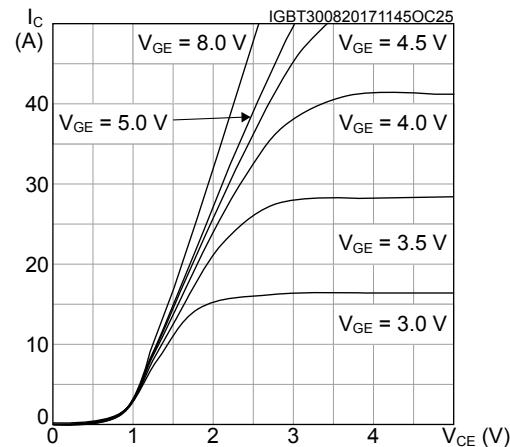
**Figure 2.**  $V_{CE(sat)}$  vs junction temperature ( $I_C = 10 \text{ A}$ )



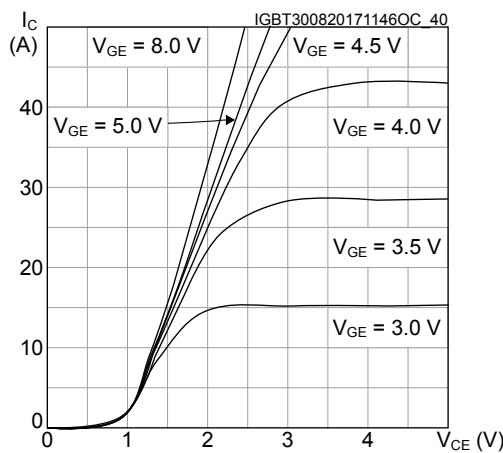
**Figure 3.** Self-clamped inductive switching current



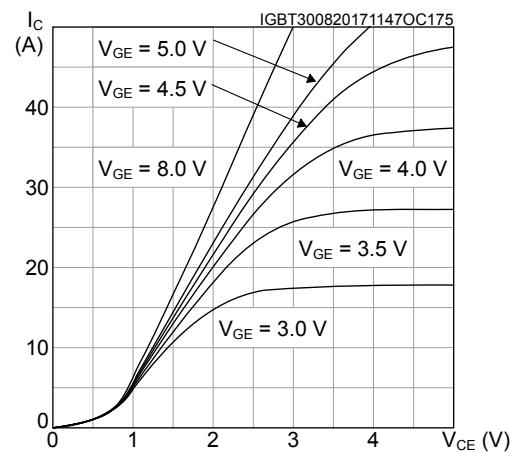
**Figure 4.** Output characteristics ( $T_J = 25 \text{ }^\circ\text{C}$ )

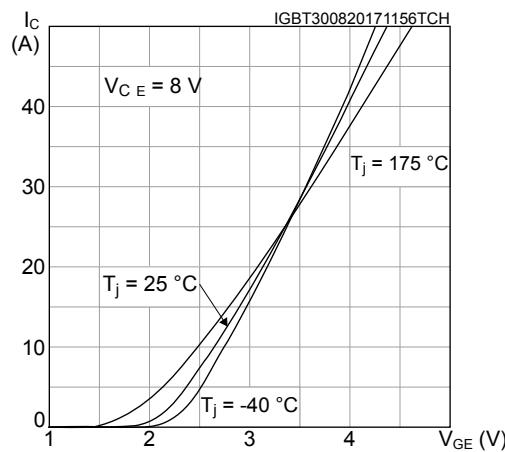
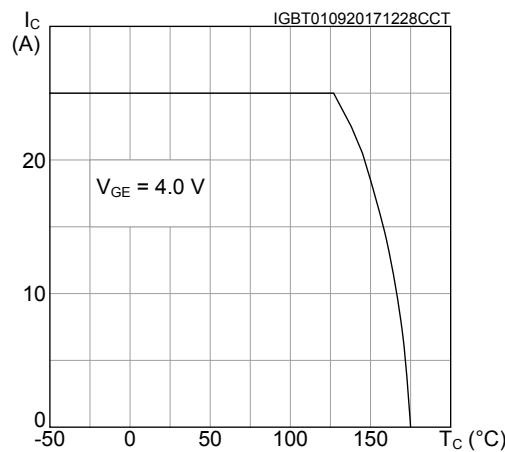
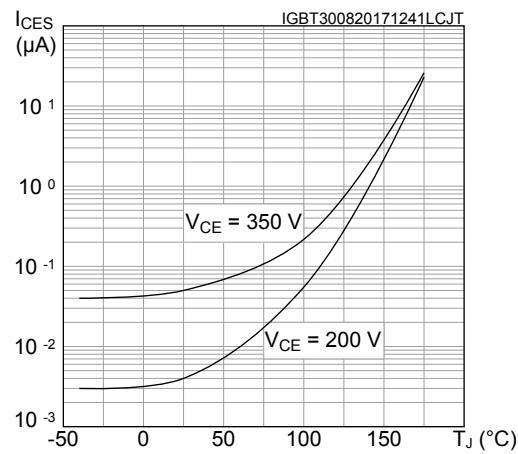
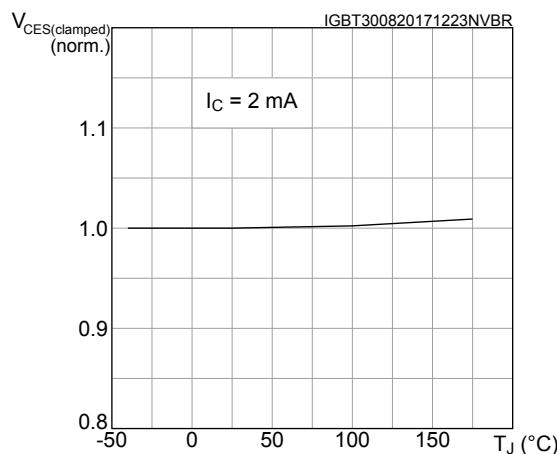
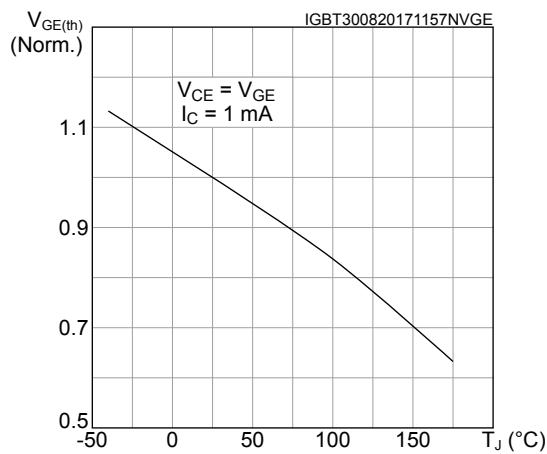
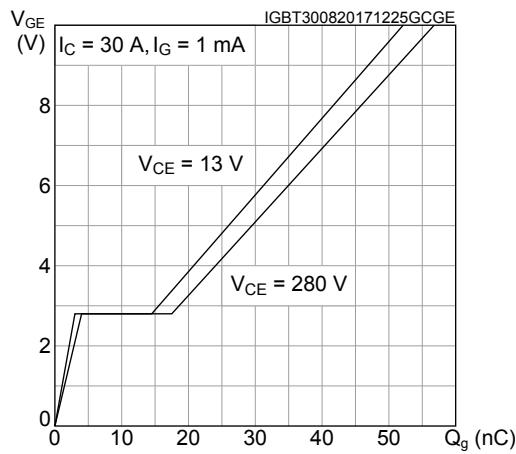


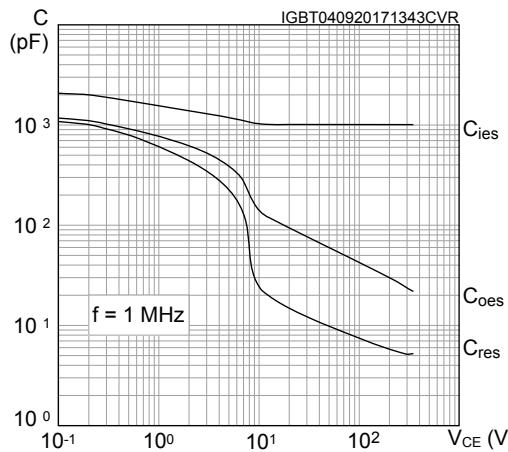
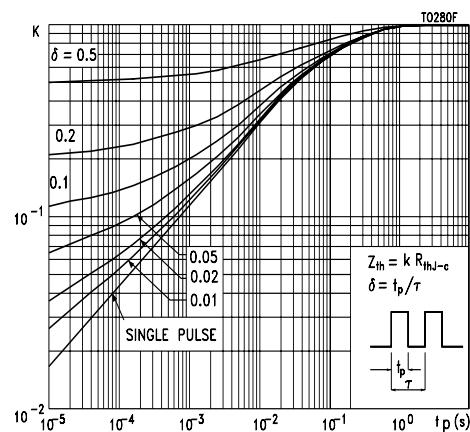
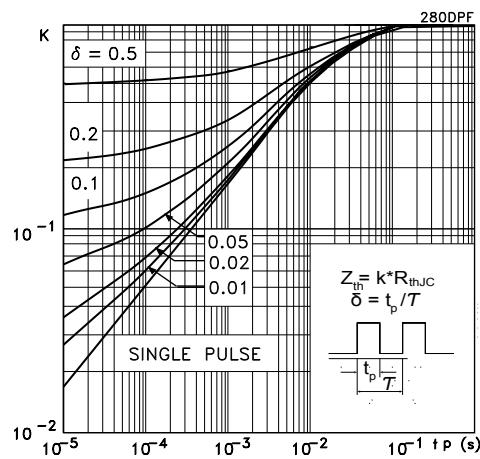
**Figure 5.** Output characteristics ( $T_J = -40 \text{ }^\circ\text{C}$ )



**Figure 6.** Output characteristics ( $T_J = 175 \text{ }^\circ\text{C}$ )

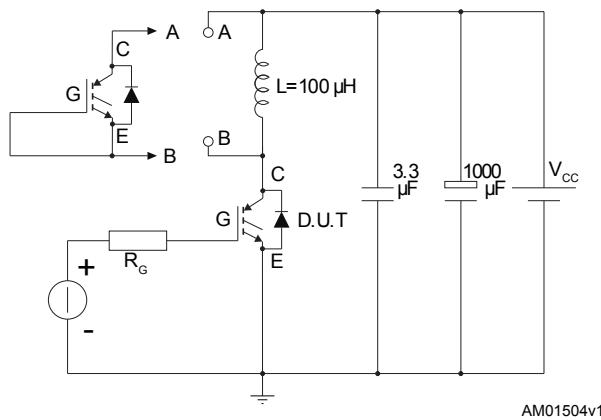


**Figure 7. Transfer characteristics**

**Figure 8. Collector current vs case temperature**

**Figure 9. Leakage current vs temperature**

**Figure 10. Normalized  $V_{CES(\text{clamped})}$  vs temperature**

**Figure 11. Normalized  $V_{GE(\text{th})}$  vs temperature**

**Figure 12. Gate charge vs gate-emitter voltage**


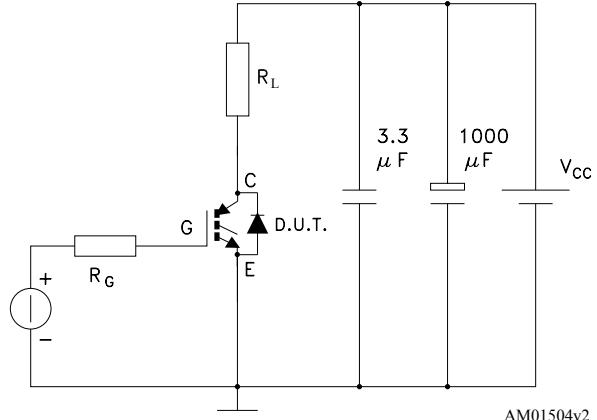
**Figure 13. Capacitance variations**

**Figure 14. Thermal impedance for D<sup>2</sup>PAK**

**Figure 15. Thermal impedance for DPAK**


### 3 Test circuits

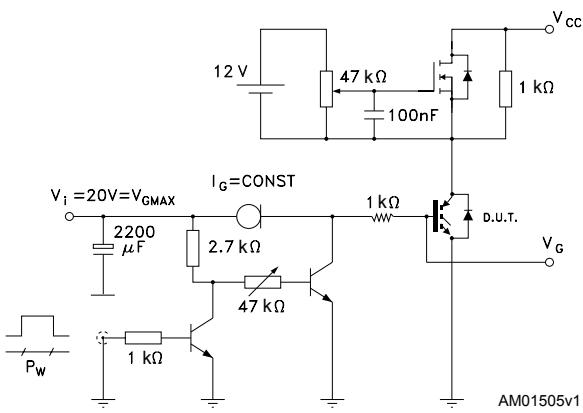
**Figure 16.** Test circuit for inductive load switching



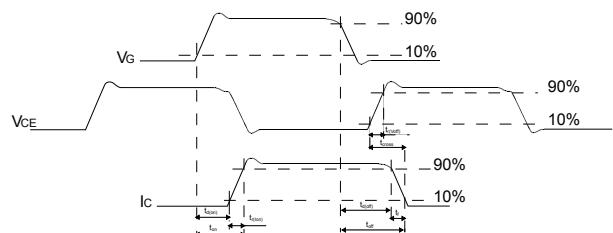
**Figure 17.** Test circuit for resistive load switching



**Figure 18.** Gate charge test circuit



**Figure 19.** Switching waveform

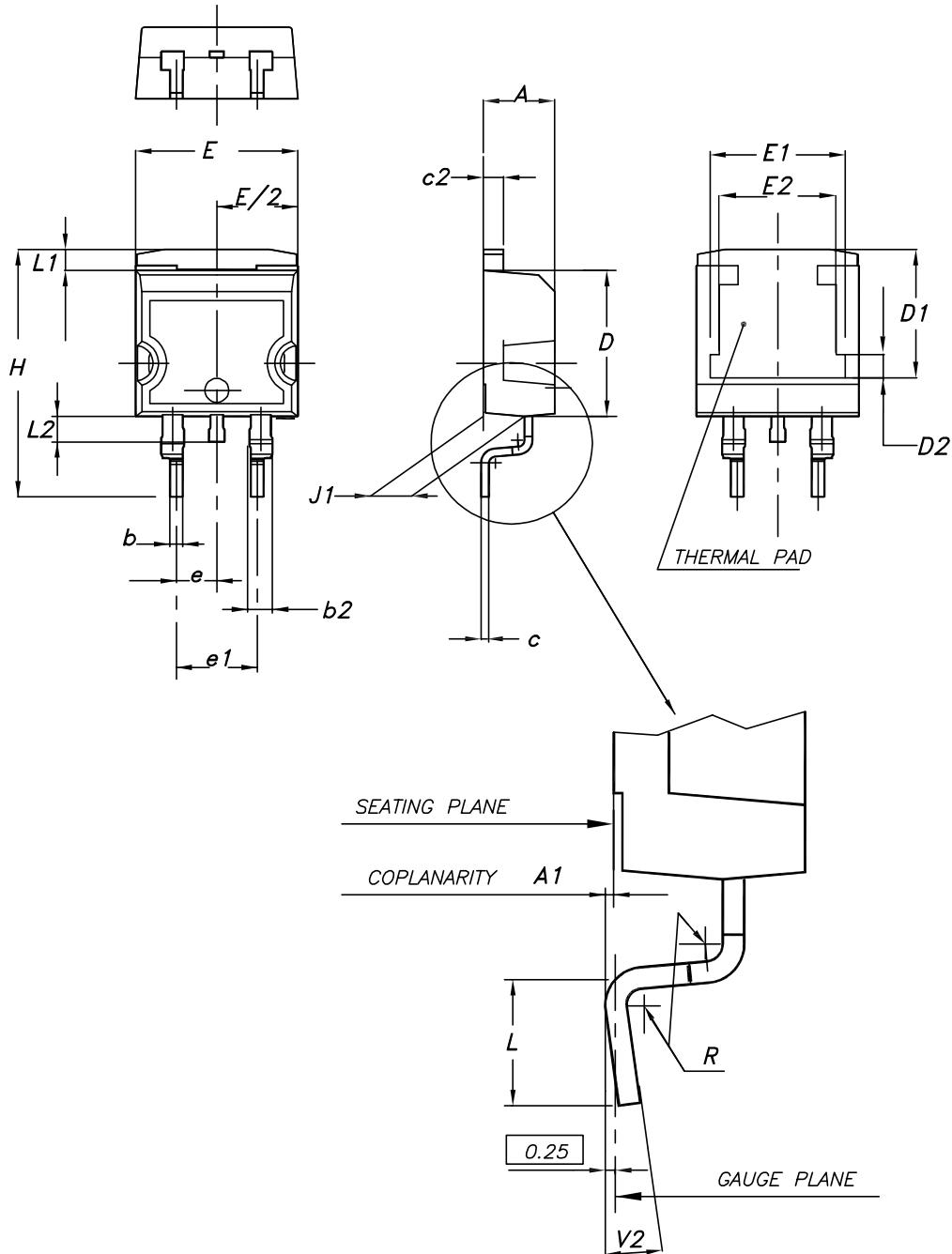


## 4 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK is an ST trademark.

### 4.1 D<sup>2</sup>PAK (TO-263) type A package information

Figure 20. D<sup>2</sup>PAK (TO-263) type A package outline

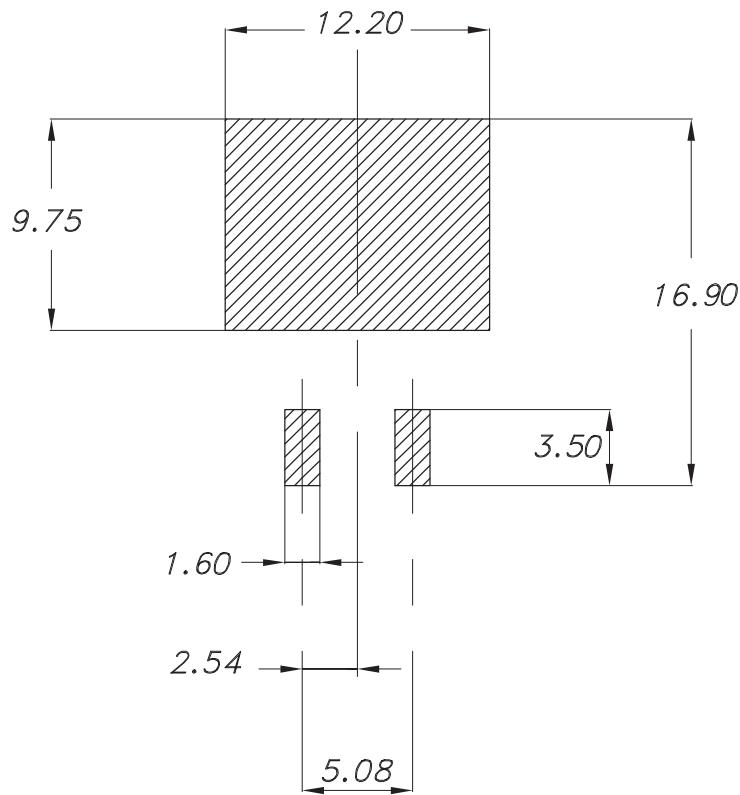


0079457\_26

**Table 7.** D<sup>2</sup>PAK (TO-263) type A package mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	4.40		4.60
A1	0.03		0.23
b	0.70		0.93
b2	1.14		1.70
c	0.45		0.60
c2	1.23		1.36
D	8.95		9.35
D1	7.50	7.75	8.00
D2	1.10	1.30	1.50
E	10.00		10.40
E1	8.30	8.50	8.70
E2	6.85	7.05	7.25
e		2.54	
e1	4.88		5.28
H	15.00		15.85
J1	2.49		2.69
L	2.29		2.79
L1	1.27		1.40
L2	1.30		1.75
R		0.40	
V2	0°		8°

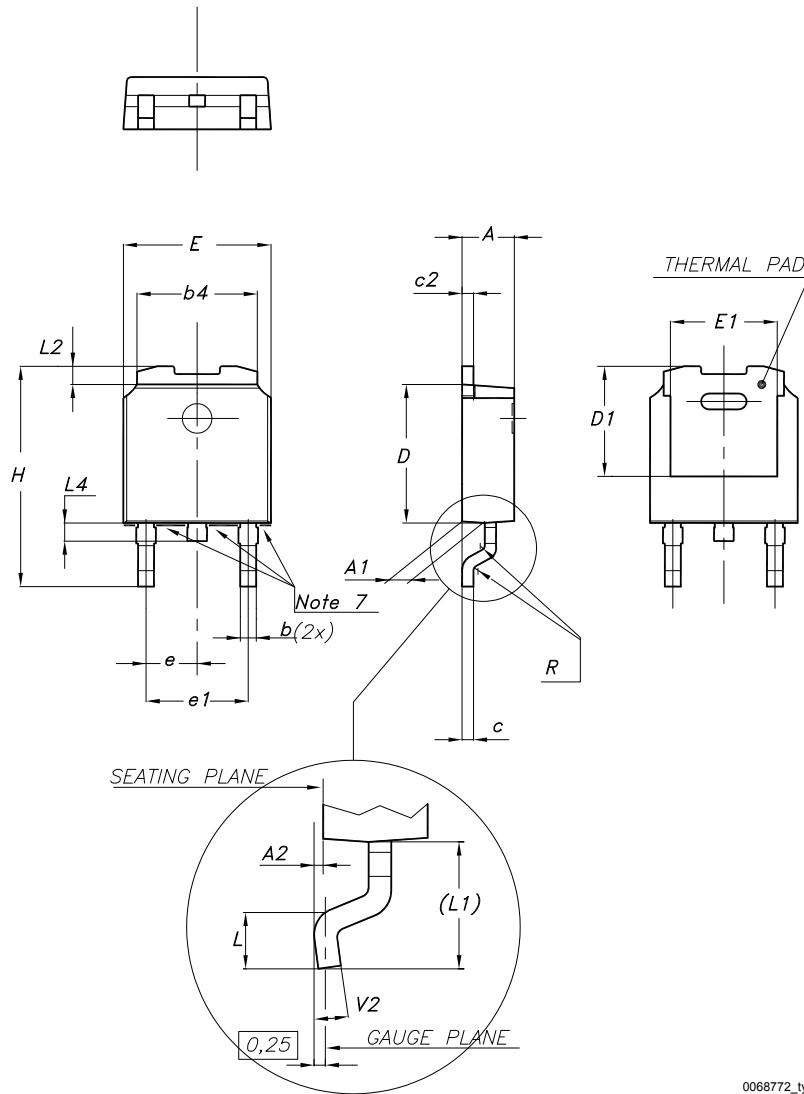
**Figure 21. D<sup>2</sup>PAK (TO-263) recommended footprint (dimensions are in mm)**



0079457\_Rev26\_footprint

## 4.2 DPAK (TO-252) type A2 package information

**Figure 22.** DPAK (TO-252) type A2 package outline

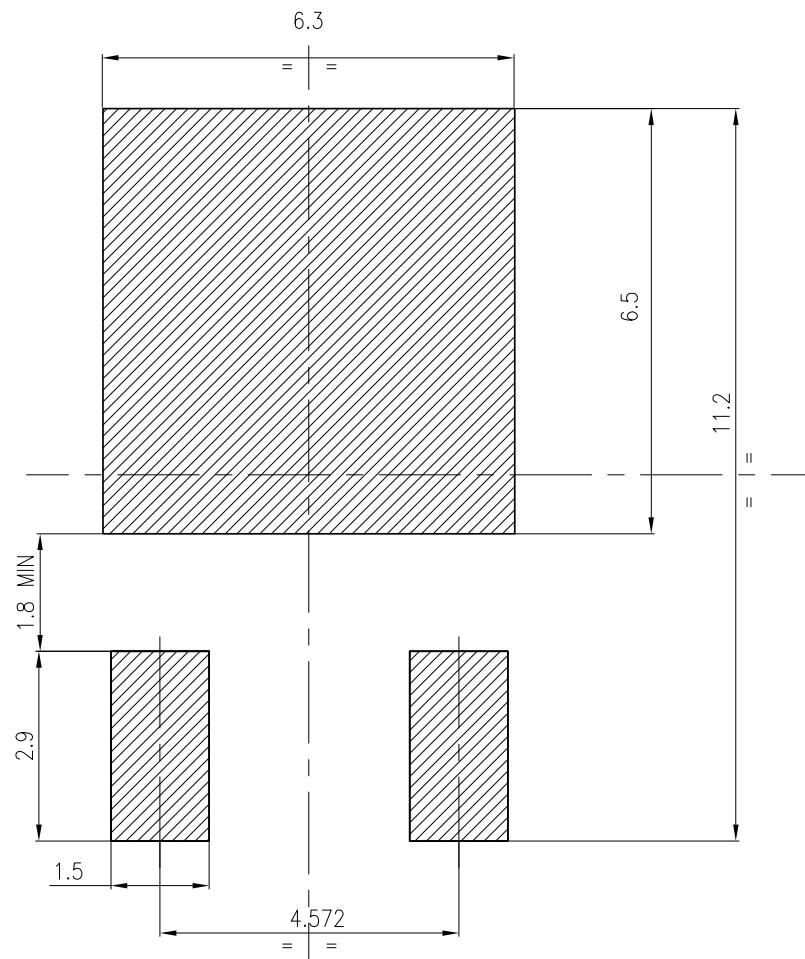


0068772\_type-A2\_rev31

Table 8. DPAK (TO-252) type A2 mechanical data

Dim.	mm		
	Min.	Typ.	Max.
A	2.20		2.40
A1	0.90		1.10
A2	0.03		0.23
b	0.64		0.90
b4	5.20		5.40
c	0.45		0.60
c2	0.48		0.60
D	6.00		6.20
D1	4.95	5.10	5.25
E	6.40		6.60
E1	5.10	5.20	5.30
e	2.159	2.286	2.413
e1	4.445	4.572	4.699
H	9.35		10.10
L	1.00		1.50
L1	2.60	2.80	3.00
L2	0.65	0.80	0.95
L4	0.60		1.00
R		0.20	
V2	0°		8°

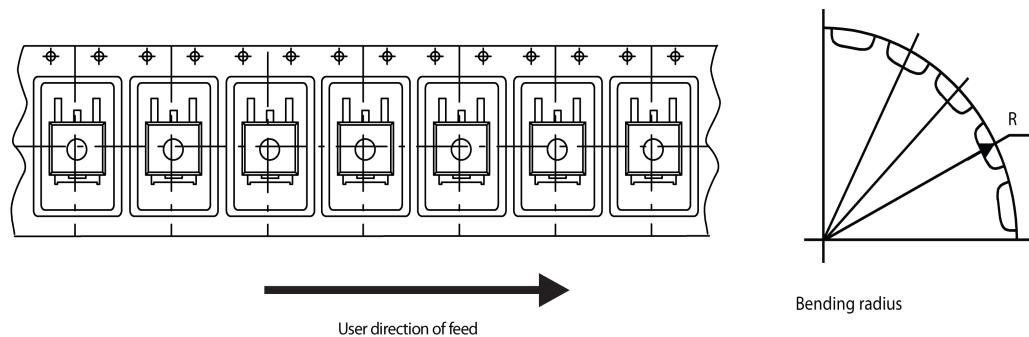
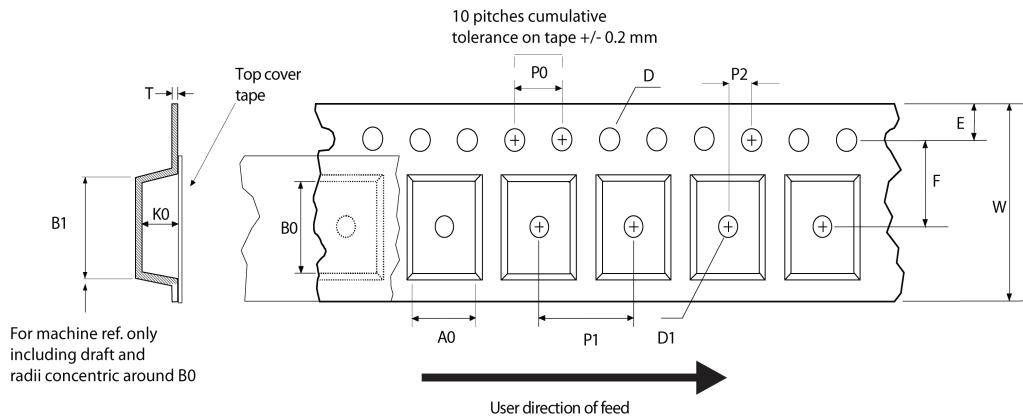
**Figure 23. DPAK (TO-252) recommended footprint (dimensions are in mm)**



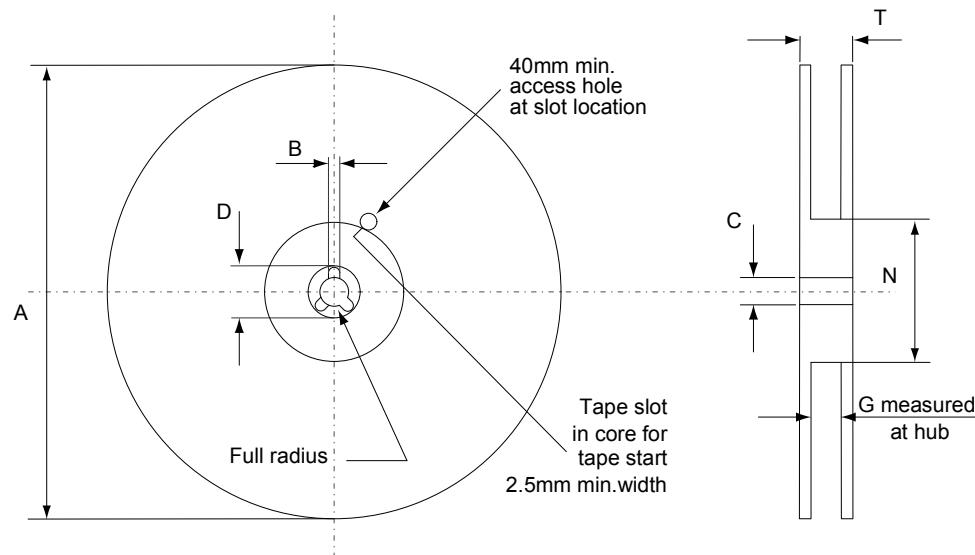
FP\_0068772\_32

#### 4.3 D<sup>2</sup>PAK and DPAK packing information

**Figure 24. Tape outline**



AM08852v1

**Figure 25. Reel outline**


AM06038v1

**Table 9. D<sup>2</sup>PAK tape and reel mechanical data**

Tape			Reel		
Dim.	mm		Dim.	mm	
	Min.	Max.		Min.	Max.
A0	10.5	10.7	A		330
B0	15.7	15.9	B	1.5	
D	1.5	1.6	C	12.8	13.2
D1	1.59	1.61	D	20.2	
E	1.65	1.85	G	24.4	26.4
F	11.4	11.6	N	100	
K0	4.8	5.0	T		30.4
P0	3.9	4.1			
P1	11.9	12.1	Base quantity		1000
P2	1.9	2.1	Bulk quantity		1000
R	50				
T	0.25	0.35			
W	23.7	24.3			

Table 10. DPAK tape and reel mechanical data

Tape			Reel		
Dim.	mm		Dim.	mm	
	Min.	Max.		Min.	Max.
A0	6.8	7	A		330
B0	10.4	10.6	B	1.5	
B1		12.1	C	12.8	13.2
D	1.5	1.6	D	20.2	
D1	1.5		G	16.4	18.4
E	1.65	1.85	N	50	
F	7.4	7.6	T		22.4
K0	2.55	2.75			
P0	3.9	4.1	Base qty.		2500
P1	7.9	8.1	Bulk qty.		2500
P2	1.9	2.1			
R	40				
T	0.25	0.35			
W	15.7	16.3			

## Revision history

**Table 11. Document revision history**

Date	Revision	Changes
30-Oct-2015	1	First release.
01-Sep-2017	2	Modified <i>Table 2: "Absolute maximum ratings"</i> , <i>Table 3: "Thermal data"</i> , <i>Table 4: "Static characteristics"</i> and <i>Table 5: "Dynamic characteristics"</i> . Added <i>Section 2.1: "Electrical characteristics (curves)"</i> . Modified <i>Section 4: "Package information"</i> . Minor text changes.
06-Sep-2017	3	Modified <i>Figure 2: "V<sub>CE(sat)</sub> vs. junction temperature (I<sub>C</sub> = 6.0 A)"</i> , <i>Figure 4: "Self clamped inductive switching current vs. inductance"</i> and <i>Figure 11: "Normalized V<sub>CES(clamped)</sub> vs. junction temperature"</i> . Minor text changes.
11-Sep-2017	4	Modified <i>Section 4.1: "D<sup>2</sup>PAK (TO-263) type A package information"</i> . Minor text changes.
02-Nov-2017	5	Updated <i>Table 4: "Static characteristics"</i> . Minor text changes
21-Feb-2018	6	Removed maturity status indication from cover page. The document status is production data. Updated <i>Section 1 Electrical ratings</i> , <i>Table 2. Thermal data</i> and <i>Table 3. Static characteristics</i> . Minor text changes
08-Feb-2023	7	Updated <i>Section 1 Electrical ratings</i> . Updated <i>Table 6. Inductive load switching characteristics</i> .

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